Instructions for Preparing PDF Abstracts for “ISCSI-X & ICSI/ISTDM2025”

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Katsunori Makihara\*1, and Tatsuro Maeda2

1Graduate School of Engineering, Nagoya University

Furo-cho, Chikusa-ku, Nagoya, 464-8603, Japan
Tel: +81-52-789-3588, E-mail: makihara.katsunori.n6@f.mail.nagoya-u.ac.jp

2National Institute of Advanced Industrial Science and Technology, Tsukuba, Ibaraki 305-8562, Japan



Fig. 1. Reduction of equivalent oxide thickness vs. year referred from the 2002 ITRS road map. This is an example.

1. Introduction

This set of instructions is given in the style and format to be used by authors preparing pdf abstracts for either “The 10th International Symposium on Control of Semiconductor Interfaces (ISCSI-X), The International Conference on Silicon Epitaxy and International SiGe Technology and Device Meeting (ICSI/ISTDM 2025)”. Papers to be presented at the symposium will be selected by the program committee on the basis of the content from submitted abstracts. The abstracts should clearly and concisely state the specific results of the work and its originality. The abstracts of accepted papers will be stored as received in USB memory or CD-R that will be distributed, instead of a book of abstracts, at the symposium. All the authors of invited and contributed papers are expected to carefully follow the instructions written in this template.

**Table 1** Brief Instructions

Format A4 size (or 8.5”×11”) white bond papers

Type single-spaced in two columns (column separation: 5 mm)

Typing area: 17.0 cm × 24.7 cm

Margins: 25 mm for top & bottom in A4 (17 mm in US letter)

20 mm for left & right in A4 (23 mm in US letter)

Desirable fonts: Time New Roman

Fonts’ sizes & style: 16 points **bold** for **title** (capital letters)

12 points for author/affiliation section and main text

12 points **bold** for **section headings** in the main text

10 points for References, Acknowledgment(s), Figure & Table captions

Section separation: single blank line

References: designate by square brackets as [1]

**2. General Instructions**

The submitted abstracts must be written in English with camera-ready quality in two pages including all figures and tables. The body of the abstracts must be prepared to fit within an area of 17.0 cm × 24.7 cm in A4-size (or 8.5'' × 11'': US-letter-size) white bond paper. For A4 size papers, set top and bottom margins to 25 mm and left and right margins are recommended to be 20 mm. The first page of abstract should be headed by the title, author(s), affiliation(s), address(es), contact author's phone number, fax number and e-mail address.

The title should be written with bold letters and use capital letters for the initial letter of each word except articles, prepositions and conjunctions. Place a blank line between the title and author name(s), and between the author address(es) and the main text. The main text of the abstract must be single-spaced throughout in two columns with full justification. Set the column separation to 5 mm. A blank line is to be placed between the sections but no blank lines between the paragraphs in each section. The section headings should be given by bold letters in capitalization.

*Fonts*

Font styles and sizes as specified in Table 1 are desirable.

*Figures and Tables*

A blank line is to be placed between the text and the figures and tables. Large figures and tables may span both columns. Photographs should have a high contrast in black and white. Figure captions should be placed just below the corresponding figures whereas table captions should be located just above the corresponding tables.

*References*

All the references are indicated in the main text by a number n in square brackets on the line like [n], and the full reference should be given in a numerical list at the end of the abstract.

3. Submitting the abstracts

The authors are requested to check spelling and carefully proofread their abstracts. Sending the PDF-format abstract file and filling up the application form on a submission World Wide Web site (the site information will be announced at the common symposium/meeting website:

**https://iscsi.sakura.ne.jp/iscsi10/abstract-submission/**

 with following the guide.

The deadline for receipt of the abstracts is

**July 10th, 2025**

Please note that no submission by Fax or mail will be accepted. The author will be notified of the committee’s decision on the submitted abstracts tentatively from late August through mid-September 2025.

4. Conference Proceedings

The Conference Proceedings will be published as a special issue of Materials Science in Semiconductor Processing. The authors are requested to prepare their manuscript as an original paper and submit it via the Elsevier’s Editorial System (EES) at https://www.journals.elsevier.com/materials-science-in-semiconductor-processing/. Your paper will be published after the usual reviewing process.

5. Conclusions

A model abstract for the Symposium has been given.

Acknowledgment

The committee members concerned would like to express sincere thanks to all the contributors to the ISCSI-X & ICSI/ISTDM2025 for their cooperation in the program.

References

[1] Author(s): the usual abbreviated title of the journal, the volume number (year) the first page number.

[2] Author(s): *Extended Abstracts of 4th Intern. Symp. on Control of Semiconductor Interfaces,* Karuizawa, 2002, p.1.